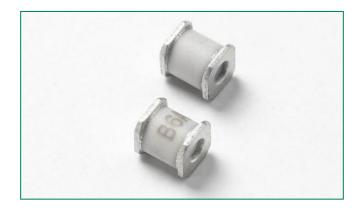


CG6 Series









Agency Approvals

| AGENCY | AGENCY FILE NUMBER | | |
|-----------|--------------------|--|--|
| 7U | E128662 | | |
| 7U | E320116 | | |

Two Electrode GDT Graphical Symbol



Additional Information







Samples

Description

The Littelfuse CG6 series GDT is a miniature surfacemount device with a 3kA 8/20 surge rating. This ITU-T K.12 Class 1, Type 1 GDT provides protection against fast rising transients typically caused by nearby lightning events. Its low insertion loss and thus low off-state capacitance makes it compatible with high bandwidth applications up to the GHz RF range. This GDT's crowbarring characteristic protects sensitive ICs from surges as defined in ITU K.20/21/45 Basic and Enhanced Recommendations, GR-1089-CORE first level lightning Port Type 1,3, and 5, and IEC 61000-4-5, 2nd edition Level 5 and below. It is hermetically sealed using non-radioactive materials and is thus environmentally safe.

Features

- RoHS compliant and Lead-free
- Excellent Surge Withstanding Capability
- Excellent response to fast rising transients.
- Ultra Low Insertion Loss and low off-state capacitance for GHz bandwidth compatibility
- 3kA 8/20µs surge capability

- Compact SMD package offered in two squared terminals
- Non-Radioactive
- Ultra Low capacitance (< 0.3pF)
- Voltage Range 75V to 600V
- UL recognized
- Characterized according to ITU-T K.12 as a Class X, Type 1 GDT

Applications

- Broadband equipment
- CATV/Broadband equipment
- Data lines and Ethernet (up to 10GbE)
- xDSL equipment, including ADSL2. ADSL. VDSL, VDSL2 30a bandplan compatible
- IAD (Integrated Access Device)
- Set Top Box (STB)
- General telecom equipment

- Embedded Multimedia Terminal Adapter (EMTA)
- RF Connector
- Multimedia over Coax Alliance (MoCA)
- Base Station RF antenna transmitter
- G.Fast 106MHz and 212 MHz bandplans compatible
- Aerospace and Automotive

Gas Discharge Tubes CG6 Series

Electrical Characteristics

| | Device Specifications (at 25°C) | | | | | Life Ratings | | | | | | | | |
|--------|---------------------------------|--------------------------------|-----|---|---|--------------------------|-----------------------------|--|--|---|--|---------------------------------------|---|-----|
| Part | | Breakd in Volts (@100V/s | S | Impulse Break- down in Volts (@100V/µs) | Impulse Break- down In Volts (@1 kV/µs) | Insulation Resistance | Capaci- tance (@1MHz) | Max Impulse Discharge Current (8/20µs) | Max Impulse Discharge Current (10/700µs) | AC Dischage Current (50Hz, 1sec) | AC Dischage Current (Single, 9 Cycles) | DC Holdover Voltage (<150ms) | Impulse Life (10/1000µs) (50A) | |
| Number | MIN | TYP | MAX | MAX | | MIN | MAX | | | MIN | MIN | | MIN | |
| CG675 | 60 | 75 | 90 | 600 | 700 | 1GΩ | | | a | | | 52V | | |
| CG690 | 72 | 90 | 108 | 600 | 700 | @50V | | 10 Shots | | | | 52V | | |
| CG6145 | 116 | 145 | 174 | 600 | 700 | 1GΩ @100V | | | | | | 52V | | |
| CG6230 | 186 | 230 | 276 | 600 | 700 | | | | | | | 80V | | |
| CG6250 | 200 | 250 | 300 | 600 | 700 | | | 0.25 | (3kΔ) 1 | 10 Shots | 3A | 64 | 80V | 300 |
| CG6300 | 240 | 300 | 360 | 650 | 800 | | | | (150A/6kV) ² | 3A | 6A | 135V | Shots | |
| CG6350 | 280 | 350 | 420 | 750 | 900 | | | | 1 Shot at 11307,0007 | (1007 40117) | | | 135V |] |
| CG6400 | 360 | 400 | 480 | 850 | 1000 | | | JKA | | | | 135V | | |
| CG6470 | 376 | 470 | 564 | 900 | 1100 | | | | | | | 135V | | |
| CG6600 | 480 | 600 | 720 | 1000 | 1200 | 1GΩ@250V | | | | | | 135V | | |

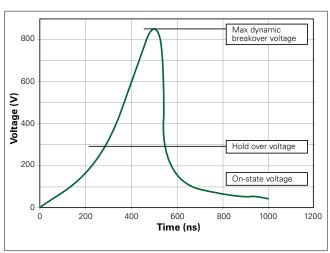
Note:

- 1. 5 x (+) and 5 x (-) applications of 3kA 8/20 μ s sec.
- 2. 5 x (+) and 5 x (-) applications of 150A 10/700 μ s sec.

Product Characteristics

| Materials | Device Tin Plated 17.5 ± 12.5 Microns Construction: Ceramic Insulator |
|-------------------------------------|---|
| Storage and Operational Temperature | -40 to +90°C |

Voltage Vs. Time Characteristic



Note: Tested per 1kV/µs waveform

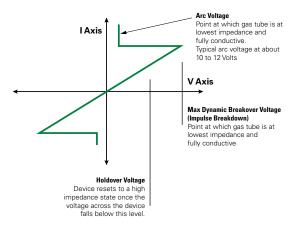
Typical Insertion Loss

| @1.0GHz = 0.03dB | |
|------------------|--|
| @1.4GHz = 0.06dB | |
| @1.8GHz = 0.09dB | |
| @2.0GHz = 0.11dB | |
| @2.4GHz = 0.13dB | |
| @2.8GHz = 0.15dB | |
| @3.1GHz = 0.17dB | |
| @3.5GHz = 0.19dB | |
| @4.0GHz = 0.22dB | |
| | |

Note: Insertion data for customer reference only, application testing needed for verification.

V-I Characteristic Curve

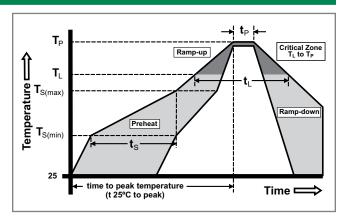
Characteristics of Gas Plasma -response to transient condition





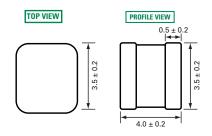
Soldering Parameters - Reflow Soldering (Surface Mount Devices)

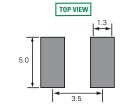
| Reflow Co | ndition | Pb – Free assembly | | |
|---------------------------------------|--|-------------------------|--|--|
| | -Temperature Min (T _{s(min)}) | 150°C | | |
| Pre Heat | -Temperature Max (T _{s(max)}) | 200°C | | |
| | -Time (Min to Max) (t _s) | 60 – 180 secs | | |
| Average rate (T _L) to pea | amp up rate (Liquidus Temp k | 3°C/second max | | |
| T _{S(max)} to T ₁ | - Ramp-up Rate | 5°C/second max | | |
| Reflow | -Temperature (T _L) (Liquidus) | 217°C | | |
| nellow | -Temperature (t _L) | 60 – 150 seconds | | |
| PeakTemp | perature (T _P) | 260 ^{+0/-5} °C | | |
| Time with | in 5°C of actual peak ure (t _p) | 10 – 30 seconds | | |
| Ramp-dov | vn Rate | 6°C/second max | | |
| Time 25°C | to peakTemperature (T _P) | 8 minutes Max. | | |
| Do not ex | ceed | 260°C | | |



Device Dimensions

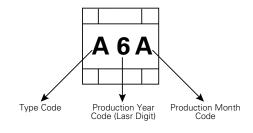
Dimensions in millimeters





Recommended Soldering Pad Layout

Product Marking



| Type Code | | |
|-----------|--------|--|
| Α | CG675 | |
| В | CG690 | |
| S | CG6145 | |
| D | CG6230 | |
| R | CG6250 | |
| E | CG6300 | |
| G | CG6350 | |
| ı | CG6400 | |
| Р | CG6470 | |
| V | CG6600 | |

| Month Code | | | |
|------------|-----------|--|--|
| Α | January | | |
| В | February | | |
| С | March | | |
| D | April | | |
| E | May | | |
| F | June | | |
| G | July | | |
| Н | August | | |
| ı | September | | |
| J | October | | |
| K | November | | |
| L | December | | |